

General Description

The MY011CNE5 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

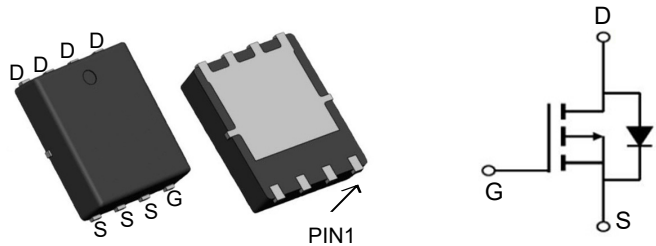


Features

V_{DSS}	-30	V
I_D	-60	A
$R_{DS(ON)}$ (at $V_{GS}=10V$)	<11	m Ω
$R_{DS(ON)}$ (at $V_{GS}=4.5V$)	<15	m Ω

Application

- Battery protection
- Load switch
- Uninterruptible power supply



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MY011CNE5	PDFN5*6-8L	011DPD	5000

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous ($T_C=25^{\circ}\text{C}$)	I_D	-60	A
Drain Current-Continuous ($T_C=100^{\circ}\text{C}$)		-24	
Drain Current-Pulsed (Note 1)	IDM	-80	A
Maximum Power Dissipation ($T_C=25^{\circ}\text{C}$)	P_D	3	W
Maximum Power Dissipation ($T_C=100^{\circ}\text{C}$)		1.3	
Single pulse avalanche energy (Note 5)	E_{AS}	231	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	$^{\circ}\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	41.67	$^{\circ}\text{C/W}$

Electrical Characteristics ($T_J=25\text{ }^{\circ}\text{C}$, unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-30	-33	-	V
Zero Gate Voltage Drain Current	ID_{SS}	$V_{DS}=-30V, V_{GS}=0V$	-	-	-1	μA
Gate-Body Leakage Current	IG_{SS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1	-1.5	-3	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=-10V, I_D=-10A$	-	-	11	m Ω
		$V_{GS}=-4.5V, I_D=-7A$	-	-	15	m Ω
Forward Transconductance	g_{FS}	$V_{DS}=-10V, I_D=-10A$	-	20	-	S
Input Capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V,$ $F=1.0MHz$	-	1750	-	PF
Output Capacitance	C_{oss}		-	215	-	PF
Reverse Transfer Capacitance	C_{rss}		-	180	-	PF
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=-15V, I_D=-10A,$ $V_{GS}=-10V, R_{GEN}=1\Omega$	-	9	-	nS
Turn-on Rise Time	t_r		-	8	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	28	-	nS
Turn-Off Fall Time	t_f		-	10	-	nS
Total Gate Charge	Q_g	$V_{DS}=-15V, I_D=-10A, V_{GS}=-10V$	-	24	-	nC
Gate-Source Charge	Q_{gs}		-	3.5	-	nC
Gate-Drain Charge	Q_{gd}		-	6	-	nC
Diode Forward Current ^(Note 2)	I_S		-	-	-12	A
Diode Forward Voltage ^(Note 3)	V_{SD}	$V_{GS}=0V, I_S=-12A$	-	-	-1.2	V

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to production
5. E_{AS} condition: $T_J=25^{\circ}\text{C}$, $V_{DD}=-15V$, $V_G=10V$, $L=0.5mH$, $R_g=25\Omega$, $I_{AS}=-34A$

Typical Characteristics

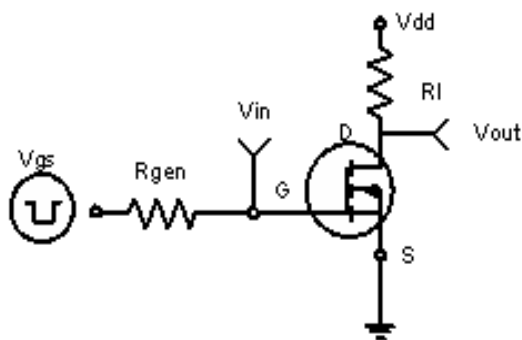


Figure 1: Switching Test Circuit

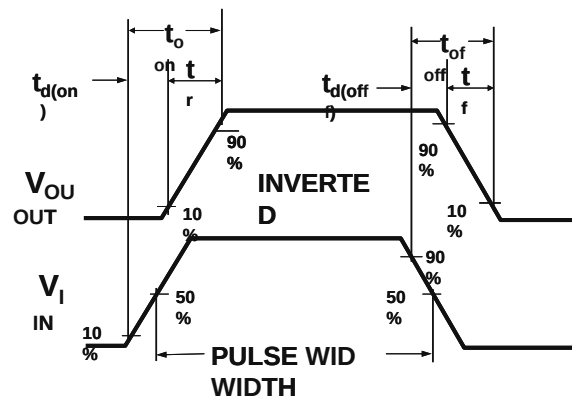
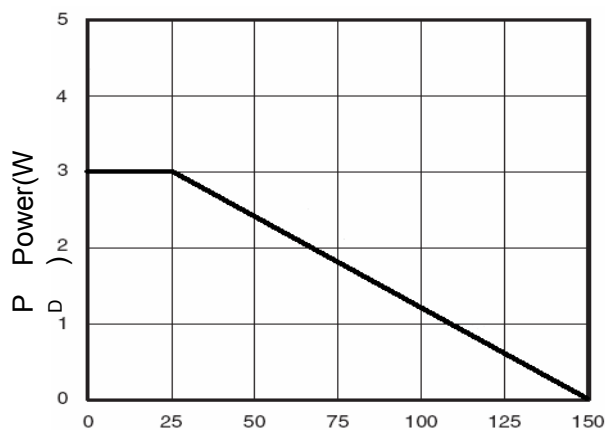
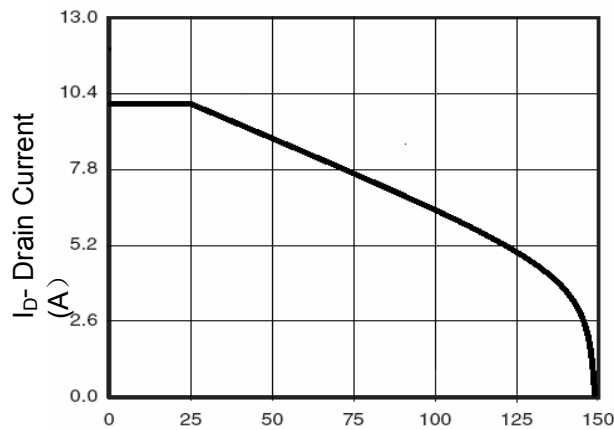


Figure 2: Switching Waveforms



T_J-Junction Temperature(°C)

Figure 3 Power Dissipation



T_J-Junction Temperature(°C)

Figure 4 Drain Current

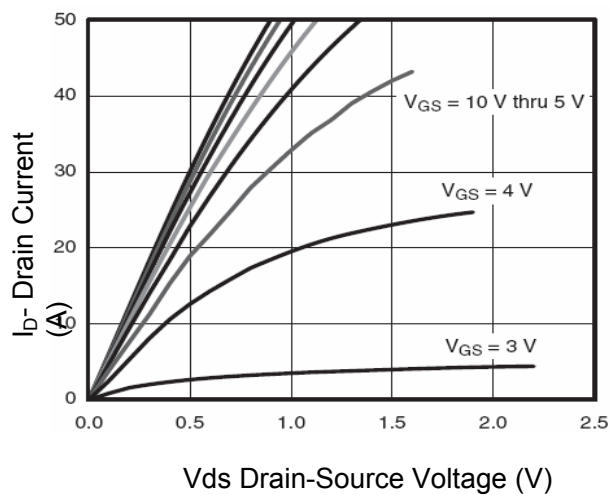


Figure 5 Output Characteristics

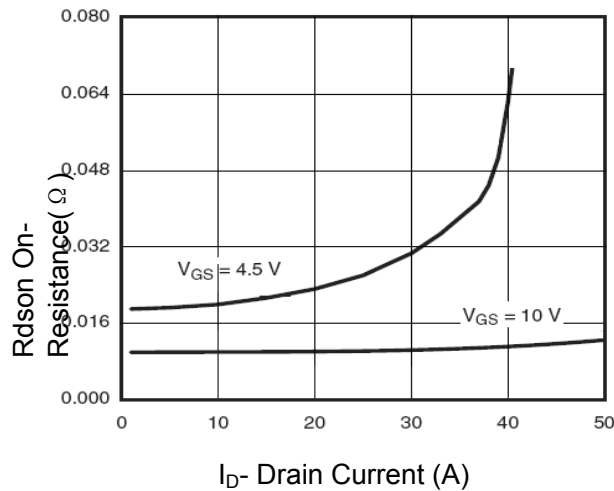
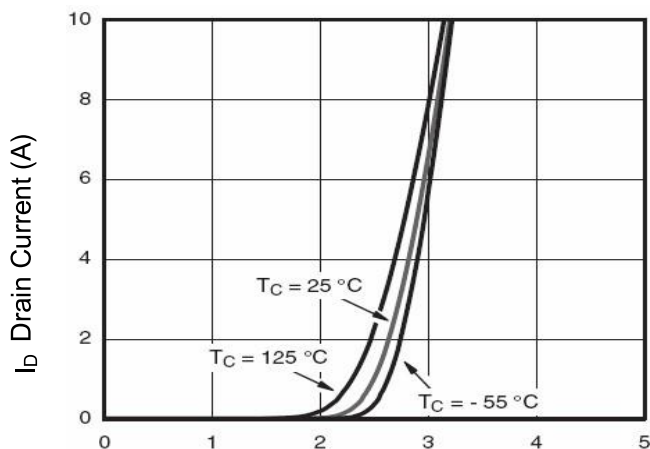
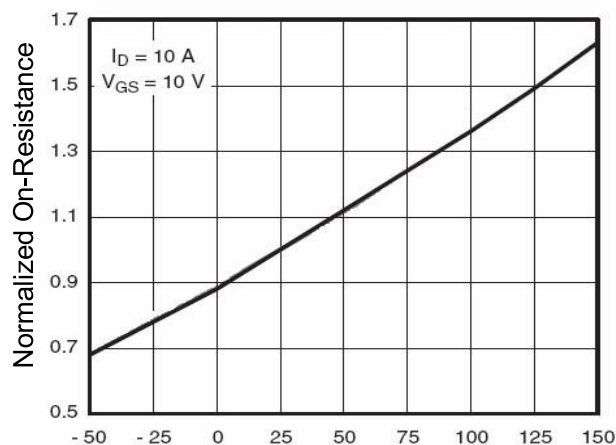


Figure 6 Drain-Source On-Resistance



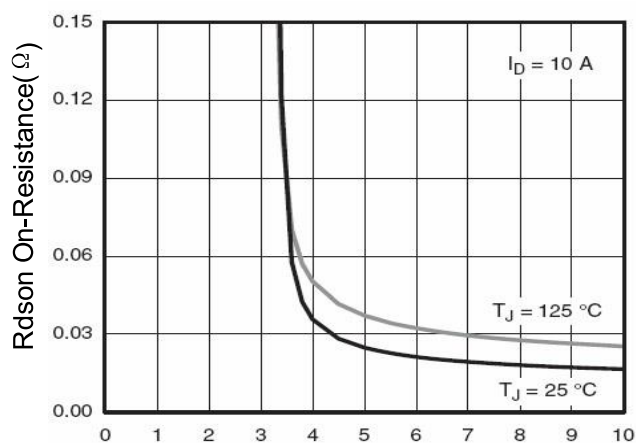
V_{GS} Gate-Source Voltage (V)

Figure 7 Transfer Characteristics



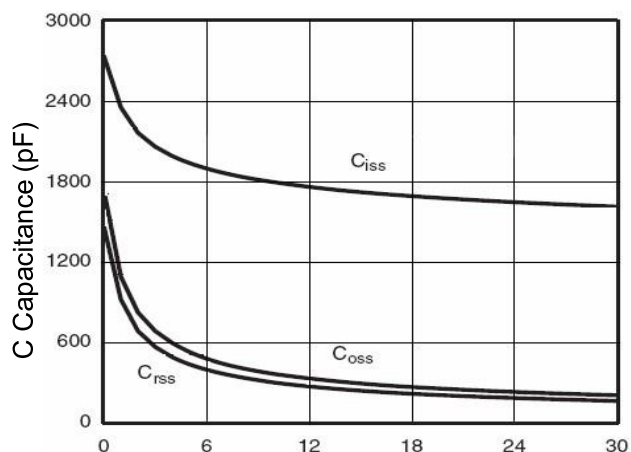
T_J - Junction Temperature (°C)

Figure 8 Drain-Source On-Resistance



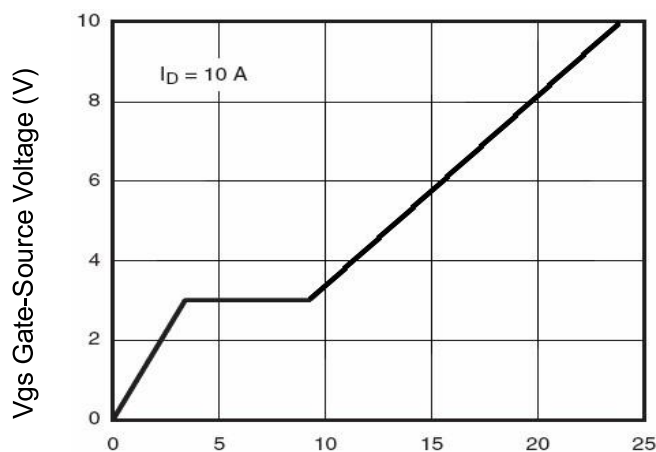
V_{GS} Gate-Source Voltage (V)

Figure 9 Rdson vs Vgs



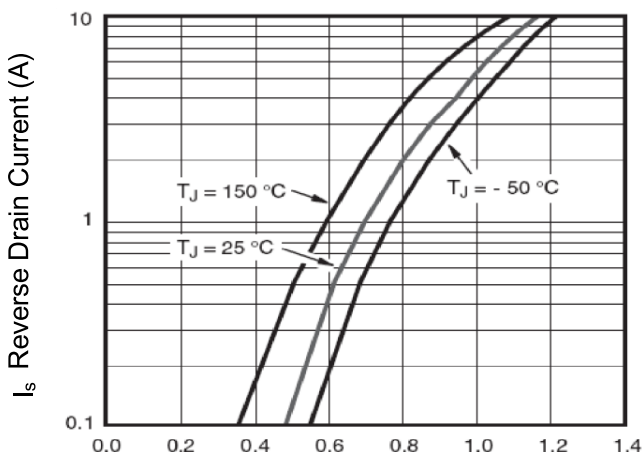
V_{DS} Drain-Source Voltage (V)

Figure 10 Capacitance vs Vds



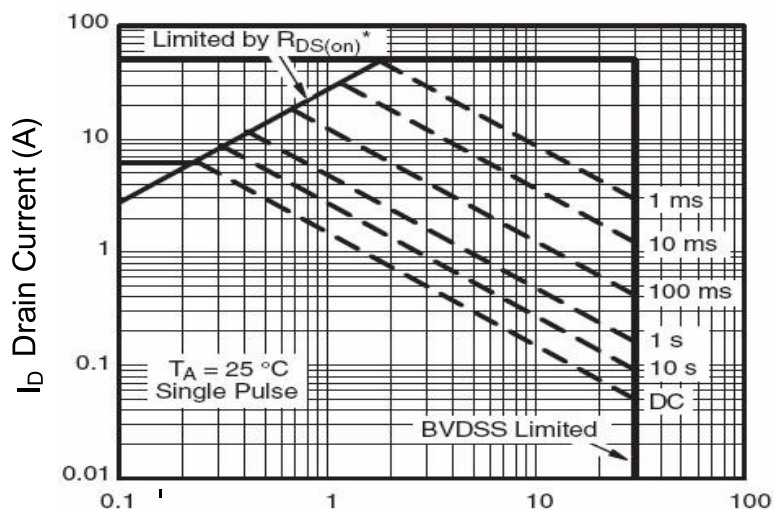
Q_g Gate Charge (nC)

Figure 11 Gate Charge



V_{SD} Source-Drain Voltage (V)

Figure 12 Source- Drain Diode Forward



Vds Drain-Source Voltage (V) **Figure 13 Safe Operation Area**

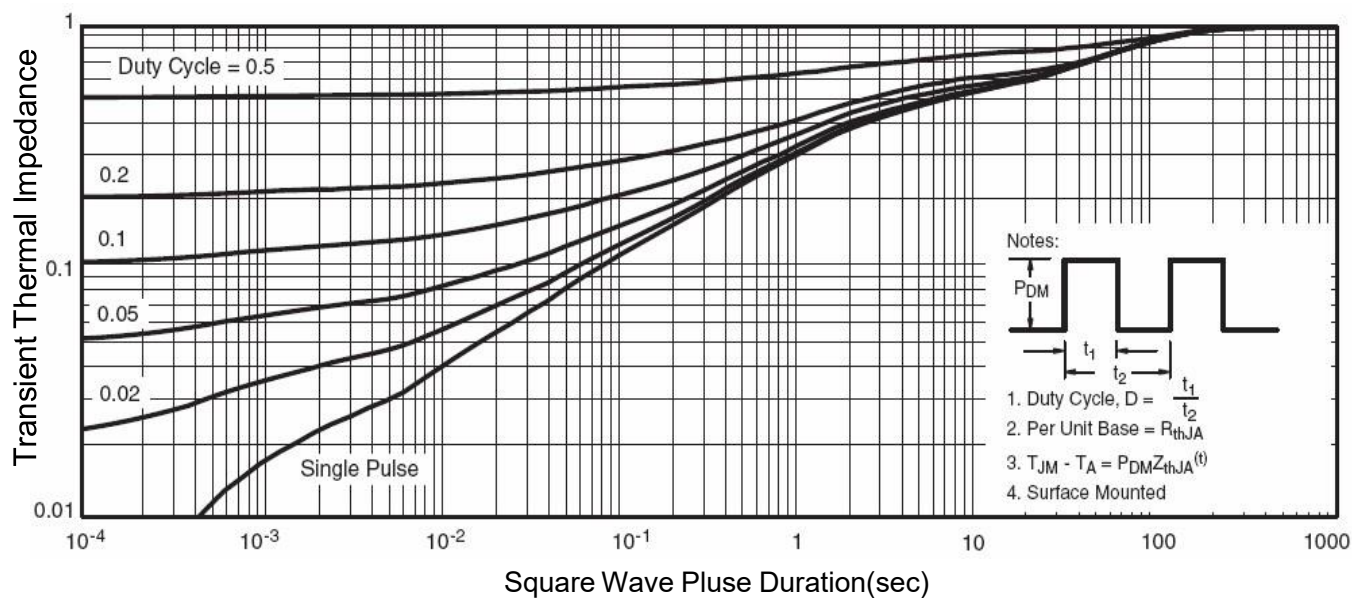
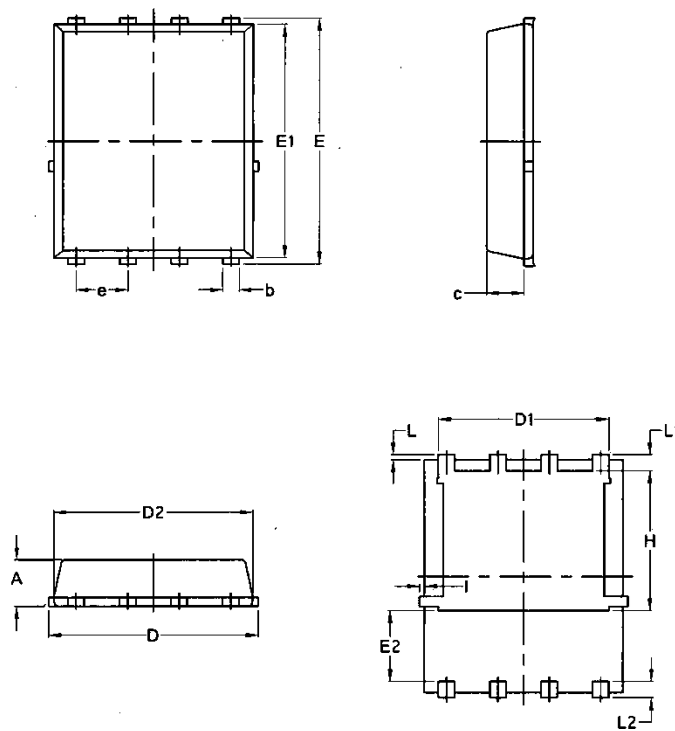


Figure 14 Normalized Maximum Transient Thermal Impedance

Package Mechanical Data-DFN5*6-8L-JQ Single



Symbol	Common			
	mm		Inch	
	Mim	Max	Min	Max
A	1.03	1.17	0.0406	0.0461
b	0.34	0.48	0.0134	0.0189
c	0.824	0.0970	0.0324	0.082
D	4.80	5.40	0.1890	0.2126
D1	4.11	4.31	0.1618	0.1697
D2	4.80	5.00	0.1890	0.1969
E	5.95	6.15	0.2343	0.2421
E1	5.65	5.85	0.2224	0.2303
E2	1.60	/	0.0630	/
e	1.27 BSC		0.05 BSC	
L	0.05	0.25	0.0020	0.0098
L1	0.38	0.50	0.0150	0.0197
L2	0.38	0.50	0.0150	0.0197
H	3.30	3.50	0.1299	0.1378
I	/	0.18	/	0.0070